NSN 5961-01-316-0502

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-316-0502 **Inclosure Material:** Ceramic **Overall Length:** 0.102 inches **Overall Diameter:** 0.118 inches **Function For Which Designed:** Varactor diode **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 reverse breakdown voltage, dc **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Precious Material And Location:** Leads plated gold **Test Data Document:** 00724-20-01088 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: